



Single Phase 8.0AMPS. Glass Passivated Bridge Rectifiers



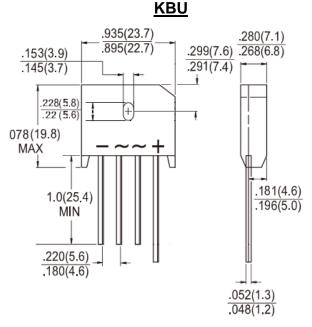


Features

- ♦ UL Recoganized File #E-326243
- ♦ Glass passivated junction
- ♦ Ideal for printed circuit board
- ♦ High case dielectric strength
- Plastic material has Underwriters Laboratory flammability Classification 94V-0
- ♦ Typical IR less than 0.1uA
- ♦ High surge current capability
- ↔ High temperature soldering guaranteed: 260°C/10 seconds at 5 lbs.,(2.3kg) tension
- Green compound with suffix "G" on packing code & prefix "G" on datecode

Mechanical Data

- ♦ Case: Molded plastic body
- Terminal: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208
- ♦ Weight: 7.2 grams
- ♦ Mounting Torque: 5 in lbs max.



Dimensions in inches and (millimeters)

KBU80XG SG SG GYWW G SG G G G Y SG Y WW SW SW

= Specific Device Code

- = Green Compound
- = Year
- = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 $^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

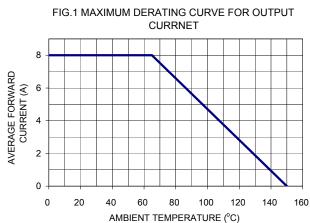
Type Number	Symbol	KBU 801G	KBU 802G	KBU 803G	KBU 804G	KBU 805G	KBU 806G	KBU 807G	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $@T_{A}{=}65^{\circ}\!\mathbb{C}$	I _{F(AV)}				8				A
Peak Forward Surge Current, 8.3 ms Single Half Sine- wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	200						А	
Rating of fusing (t<8.3mS)	l ² t				166				A ² S
Maximum Instantaneous Forward Voltage (Note 1) @ 4 A @ 8 A	V _F				1.0 1.1				V
Maximum DC Reverse Current@ T_A =25 °Cat Rated DC Blocking Voltage@ T_A =125 °C	I _R	5 500						uA	
Typical Junction Capacitance per leg (Note 2)	Cj				400				pF
Typical Thermal Resistance	$R_{_{ extsf{ heta}JA}}$ $R_{_{ hetaJC}}$	18 3						^o C/W	
Operating Temperature Range	TJ	- 55 to + 150						°C	
Storage Temperature Range	T _{STG}			- 5	55 to + 1	50			°C

Note 1 : Pulse Test with PW=300u sec, 1% Duty Cycle

Note 2 : Measured at 1MHz and applied Reverse bias of 4.0V D.C.



RATINGS AND CHARACTERISTIC CURVES (KBU801G THRU KBU807G)



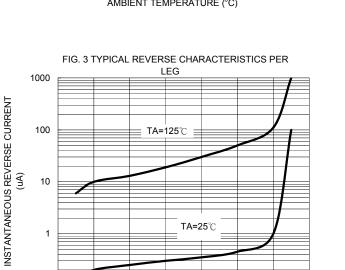
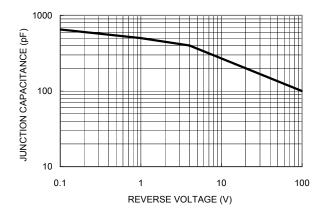


FIG. 5 TYPICAL JUNCTION CAPACITANCE



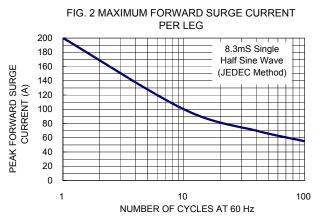


FIG. 4 TYPICAL FORWARD CHARACTERISRICS PER

